

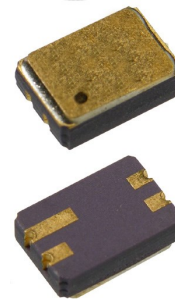
Hi-Reliability RAD Capable Optoisolator

HCC1002



Features:

- TID Capable to 100Krad (SI)/cm² ELDRS (0.1rad/s)
- Neutron capable to 1E12 neutrons (14MeV)
- Processed to MIL-STD-19500 TXV level
- 1 KV electrical Isolation

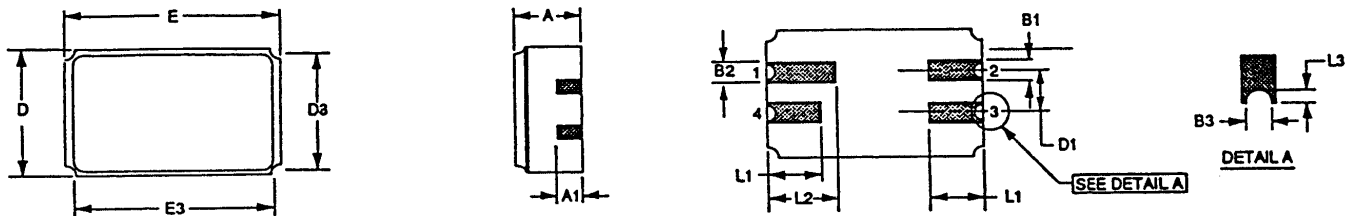


Description:

This device is similar to Optek's 4N series of optoisolators with exception of the die. It is processed to MIL-PRF-19500 and can be modified per customer SCDs. Each device consists of a IRLED & NPN transistor mounted in a hermetic 4 pin LCC SMD.

Applications:

Circuit electrical isolation in space applications such as satellites, launchers, space vehicles and planetary rovers



- 1 — Collector
- 2 — Cathode
- 3 — Anode
- 4 — Emitter

Dimensions				
Inches			Millimeters	
Ltr	Min	Max	Min	Max
A	.061	.075	1.55	1.90
A1	.026	.034	0.66	0.88
B1	.022	.028	0.56	0.71
B2	.072 Ref		1.83 Ref	
B3	.006	.022	0.15	0.56
D	.145	.155	3.68	3.93
D1	.045	.055	1.14	1.39
D3	-	.155	-	3.93
E	.215	.225	5.46	5.71
E3	-	.225	-	5.71
L1	.032	.048	0.81	1.22
L2	.072	.088	1.83	2.23
L3	.003	.007	0.08	0.18

General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

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Electrical Specifications

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Storage Temperature Range	-55° C to +150° C
Operating Temperature Range	-55° C to +150° C
Input-to-Output Isolation Voltage	$\pm 1.00\text{ kVDC}^{(1)}$
Lead Soldering Temperature (TO-78 Metal Can) [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron]	260° C ⁽²⁾
Soldering Temperature (SMD) Vapor Phase Reflow for 30 seconds	215° C

Input Diode (LED)

Forward DC Current (65° C or below)	40 mA
Reverse Voltage	2 V
Power Dissipation	60 mW ⁽³⁾

Output Phototransistor:

Continuous Collector Current	50 mA
Collector-Emitter Voltage	40 V
Power Dissipation	300 mW ⁽⁴⁾

Notes:

1. Measured with input leads shorted together and output leads shorted together.
2. RMA flux is recommended.
3. Derate linearly 1.0 mW/° C above 65° C.
4. Derate linearly 3.0 mW/° C above 25° C.

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Performance

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
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Input Diode

V_F	Forward Voltage	0.80 1.00 0.70	- - -	1.70 1.9 1.50	V	$I_F = 10.0\text{ mA}$ $I_F = 10.0\text{ mA}, T_A = -55^\circ\text{C}$ $I_F = 10.0\text{ mA}, T_A = 125^\circ\text{C}$
I_R	Reverse Current	-	-	100	μA	$V_R = 2.0\text{ V}$

Output Phototransistor

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	40	-	-	V	$I_C = 1.0\text{ mA}, I_B = 0, I_F = 0$
$V_{(BR)EBO}$	Emitter-Collector Breakdown Voltage	7	-	-	V	$I_E = 100\text{ }\mu\text{A}, I_C = 0, I_F = 0$
$I_{C(OFF)}^1$	Collector-Emitter Dark Current	-	-	100	nA	$V_{CE} = 20\text{ V}, I_B = 0, I_F = 0$
$I_{C(OFF)}^2$	Collector-Emitter Dark Current	-	-	100	μA	$V_{CE} = 20\text{ V}, I_B = 0, I_F = 0, T_A = 100^\circ\text{C}$

Coupled

$I_{C(ON)}$	On-State Collector Current	1 15 10 15	- - - -	- - - -	mA	$I_F = 1.0\text{ mA}, V_{CE} = 1.0\text{ V}, I_B = 0$ $I_F = 15.0\text{ mA}, V_{CE} = 1.0\text{ V}, I_B = 0$ $I_F = 10.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0$ $I_F = 15.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0$
		2.8 2.0	- -	- -		$I_F = 2.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0, T_A = -55^\circ\text{C}$ $I_F = 2.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0, T_A = 100^\circ\text{C}$
$V_{CE(SAT)}$	Collector-Emitter Saturation Voltage	-	-	0.30	V	$I_F = 20.0\text{ mA}, I_C = 10.0\text{ mA}, I_B = 0$
R_{IO}	Resistance (Input-to-Output)	10^{11}	-	-	Ω	$V_{I-O} = \pm 1000\text{ VDC}^{(1)}$
C_{IO}	Capacitance (Input-to-Output)	-	-	5	pF	$V_{I-O} = 0\text{ V}, f = 1.0\text{ MHz}^{(1)}$
T_R, T_F	Rise and Fall Time	-	-	20	μs	$V_{CC} = 10.0\text{ V}, I_F = 10.0\text{ mA}, R_L = 100\text{ }\Omega$

Notes:

1. Measured with input leads shorted together and output leads shorted together.

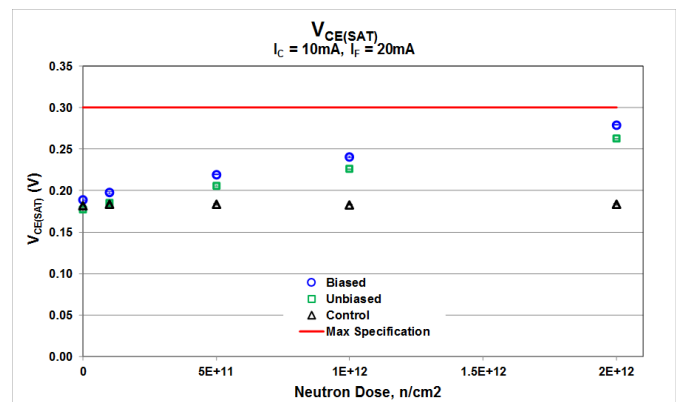
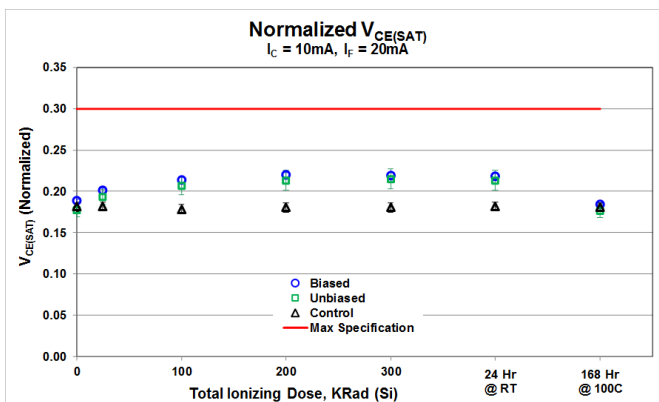
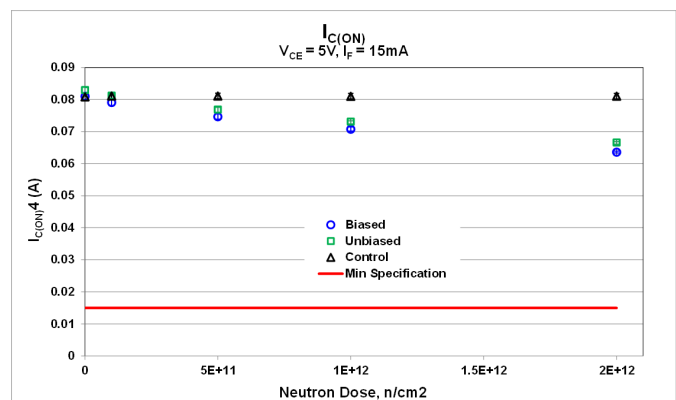
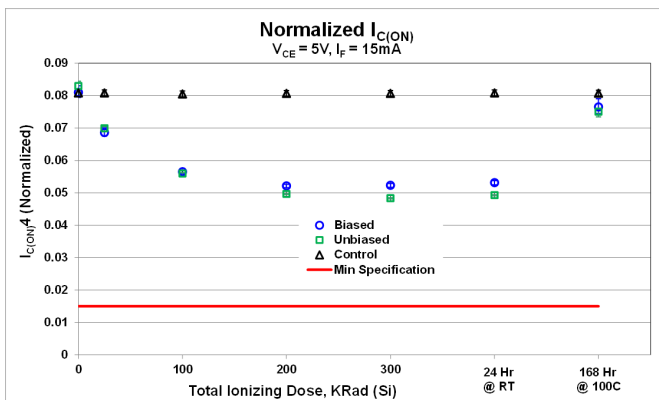
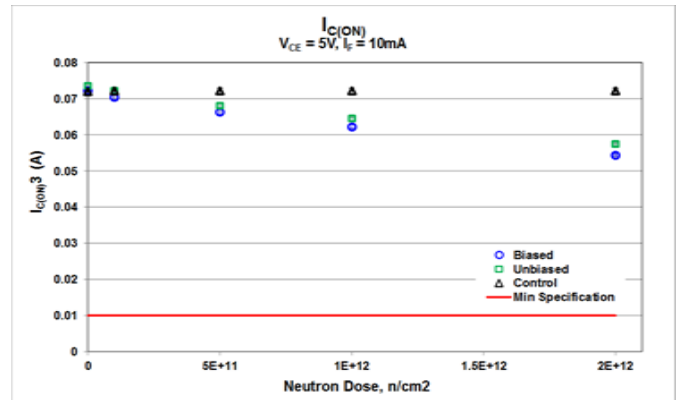
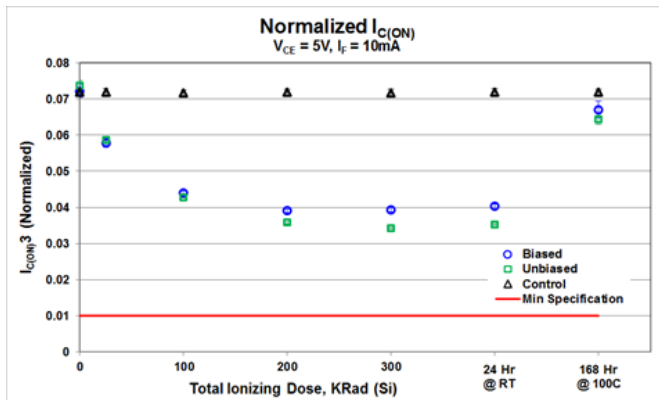
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Radiation Test Standards

- **Total Ionizing Dose:** MIL-STD-883 Method 1019.7 and ASTM F1892-06 (0.1rad (si)/s) dose rate
- **Neutron:** MIL-STD-883 Method 1017.2 and ASTM Designation: E 772—94
- **Full Radiation report available**



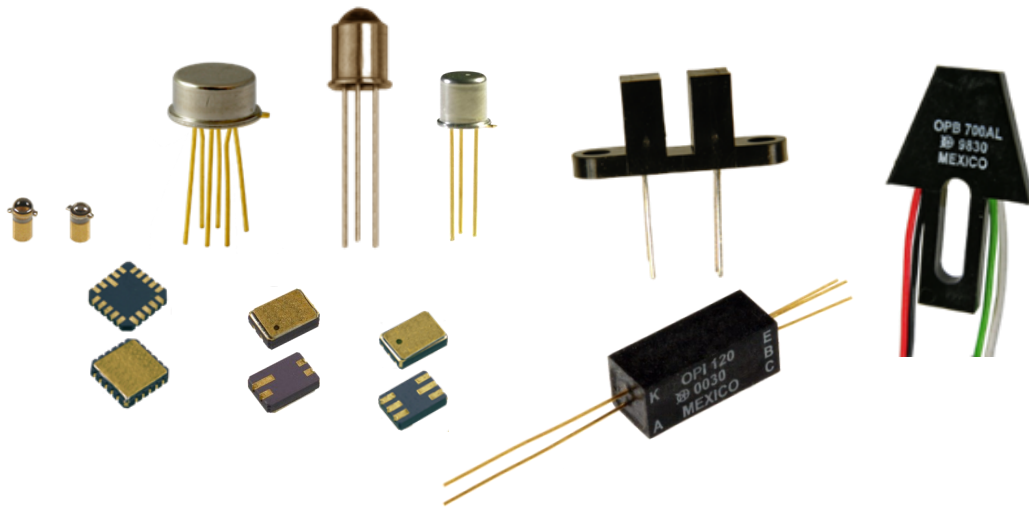
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Packaging

Package styles available:

Radiation testing was in a TO-78 can; functional & radiation samples can be supplied in discrete pairs such as, “pills” or TO-46 / TO-18 metal cans, 4 & 6 pin Hermetic Ceramic LLC, high voltage assemblies like the OPI120 and OPI150 hermetic high voltage isolators and more.



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